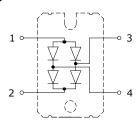


PRELIMINARY DATASHEET

Rectifier Diodes, 4x25A, 1600V, Single Phase Rectifier Bridge Configuration in Isolated SOT227 Package

- General purpose rectifiers
- Low forward voltage
- Pb-free lead finish; RoHS compliant





MAXIMUM RATINGS (per Diode), at T_j = 25°C, unless otherwise specified

Parameter	Symbol Value		Units	
Repetitive peak reverse voltage	V _{RRM}	1600	V	
Average forward current $T_C = 90^{\circ}C$	l _F	25		
Surge non-repetitive forward current $T_J = T_{jmax}$, $t_p = 10$ ms, 50Hz, Sine	I _{FSM}	300	A	
Operating junction and storage temperature	T _j , T _{stg}	-40 +150	°C	

Thermal and Isolation Characteristics

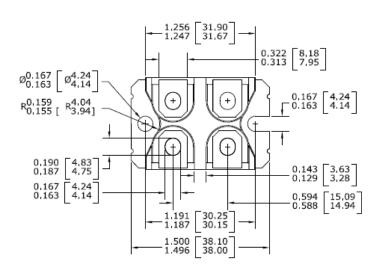
Parameter	Symbol	Max. Value	Units	
Characteristics				
Thermal resistance, junction to case	R _{thJC}	1.7	- K/W	
Thermal resistance, junction to case, module	R _{thJC}	0.43		
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-3 seconds)	V _{iso}	3000	٧	

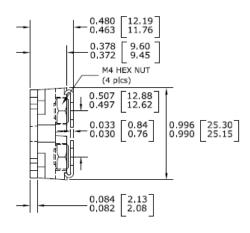
Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

Parameter	Symbol	Value			Heil
		Min.	Тур.	Max.	Unit
Static Characteristics					
Reverse leakage current At 100% Vrrm	I _R	-	-	100	μA
Forward voltage drop I _F = 25A	V _F	-	1.25	-	٧



Package Outline Drawing





Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of iQXPRZ Power Inc. components in life support appliances and systems are subject to written approval of iQXPRZ Power Inc.